100V NPN MEDIUM POWER TRANSISTOR IN SOT89

Features

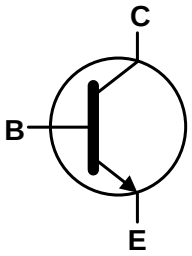
- BV_{CEO} > 100V
- BV_{ECO} > 6V
- I_C = 2.5A Continuous Collector Current
- I_{CM} = 3.5A Peak Collector Current
- $V_{CE(SAT)}$ < 100mV @ 1A
- $R_{CE(SAT)}$ = 80mΩ for a Low Equivalent On-Resistance
- Complementary PNP Type: ZXTP25100CZ
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

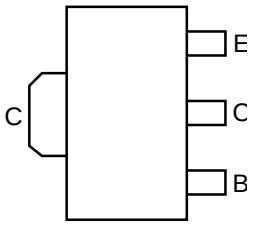
- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.05 grams (Approximate)

SOT89

Top View



Device Symbol



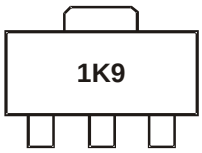
Top View
Pin Out

Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
ZXTN25100DZTA	AEC-Q101	1K9	7	12	1,000

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



1K9 = Product Type Marking Code

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	180	V
Collector-Emitter Voltage (Forward Blocking)	V_{CEX}	180	V
Collector-Emitter Voltage	V_{CEO}	100	V
Emitter-Collector Voltage (Reverse Blocking)	V_{ECO}	6	V
Emitter-Base Voltage	V_{EBO}	7	V
Continuous Collector Current	I_C	2.5	A
Peak Pulse Current	I_{CM}	3.5	A
Base Current	I_B	1	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

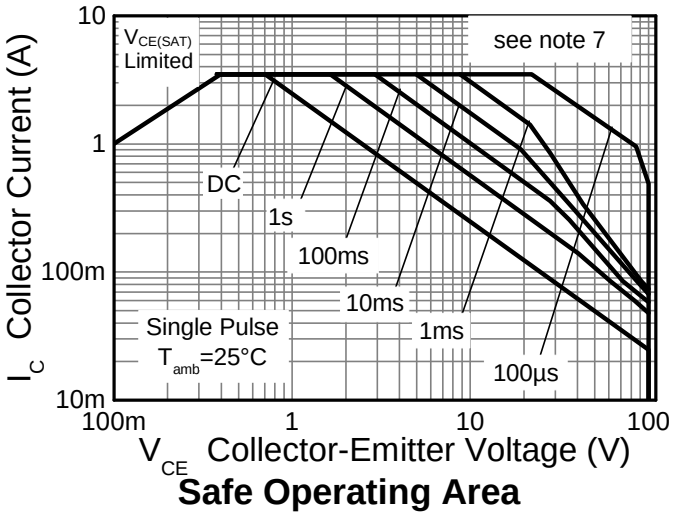
Characteristic		Symbol	Value	Unit
Power Dissipation Linear Derating Factor	(Note 5)	P_D	1.1 8.8	W mW/°C
	(Note 6)		1.8 14.4	
	(Note 7)		2.4 19.2	
	(Note 8)		4.46 35.7	
Thermal Resistance, Junction to Ambient Air	(Note 5)	$R_{\theta JA}$	117	°C/W
	(Note 6)		68	
	(Note 7)		51	
	(Note 8)		28	
Thermal Resistance, Junction to Lead	(Note 9)	$R_{\theta JL}$	7.95	
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to +150	°C

ESD Ratings (Note 10)

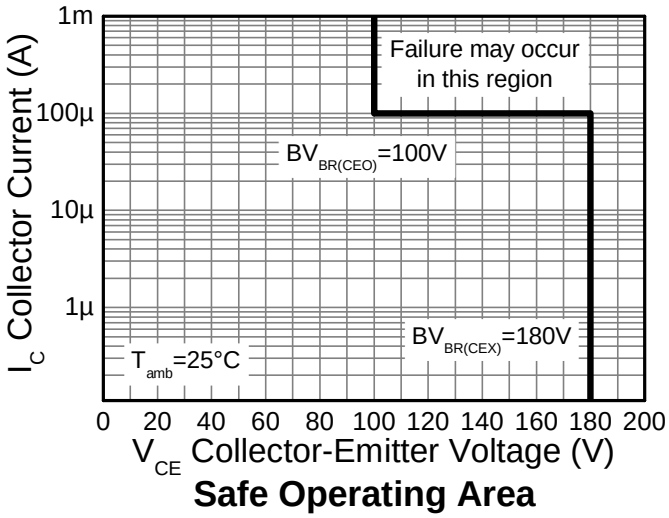
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

Notes:
5. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 0.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.
6. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
7. Same as Note 5, except the device is mounted on 50mm x 50mm 2oz copper.
8. Same as Note 7, except the device is measured at t<5 seconds.
9. Thermal resistance from junction to solder-point (on the exposed collector pad).
10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

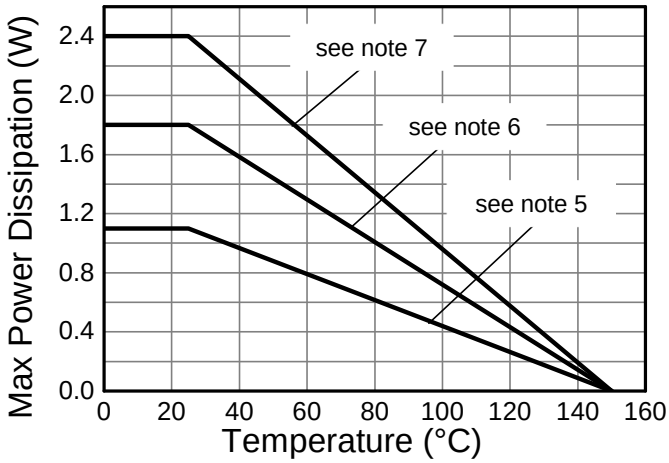
Thermal Characteristics and Derating Information



Safe Operating Area

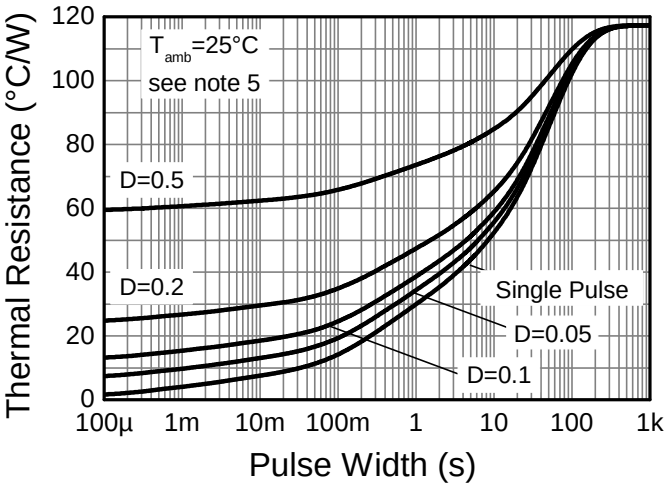


Safe Operating Area

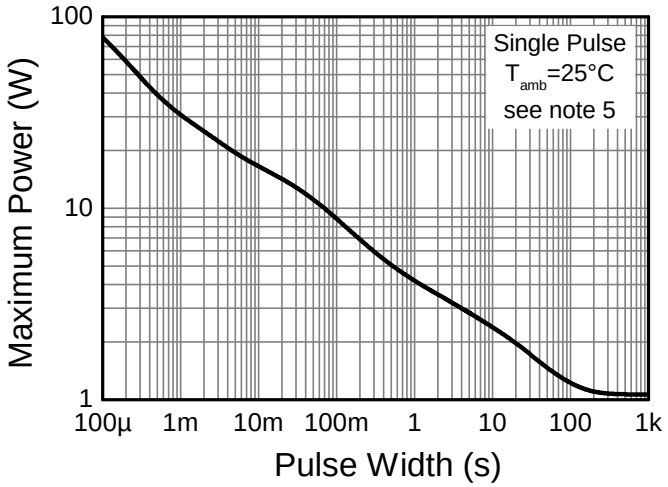


Derating Curve

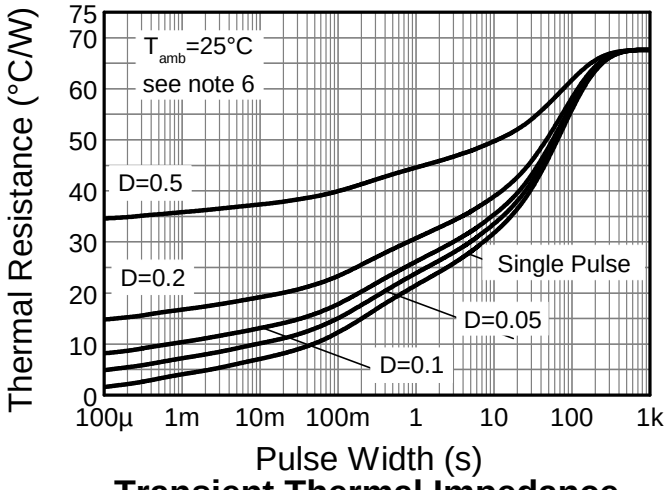
Thermal Characteristics and Derating Information



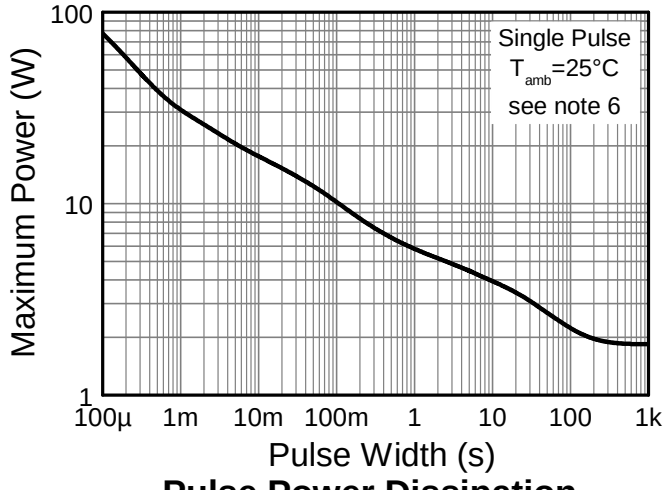
Transient Thermal Impedance



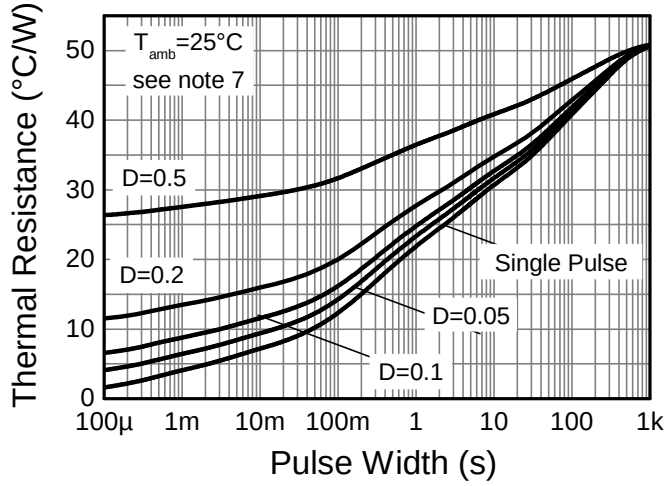
Pulse Power Dissipation



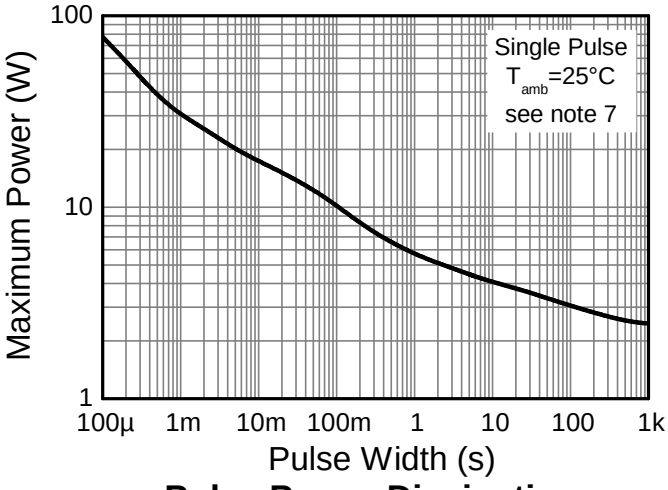
Transient Thermal Impedance



Pulse Power Dissipation



Transient Thermal Impedance



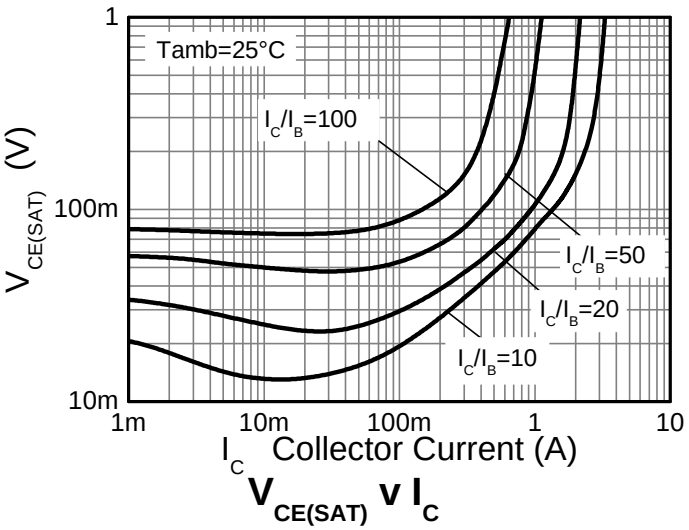
Pulse Power Dissipation

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

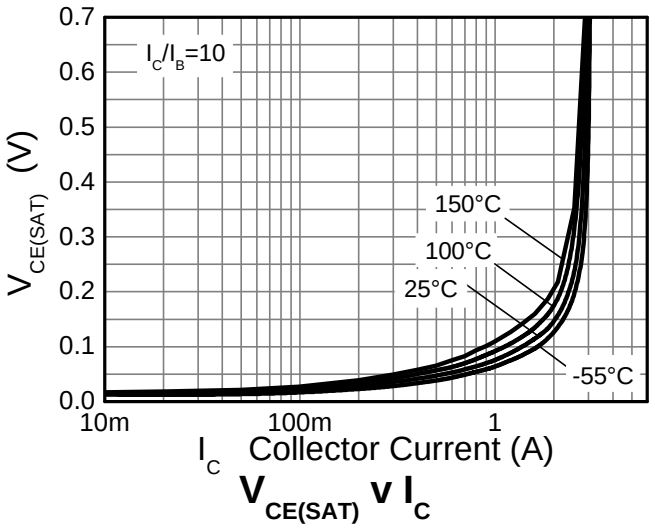
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	180	220	—	V	I_C = 100µA
Collector-Emitter Breakdown Voltage (Forward Blocking)	BV_{CEX}	180	220	—	V	I_C = 100µA, R_{BE} <1kΩ or -1V > V_{BE} > 0.25V
Collector-Emitter Breakdown Voltage (Note 11)	BV_{CEO}	100	130	—	V	I_C = 10mA
Emitter-Collector Breakdown Voltage (Reverse Blocking)	BV_{ECX}	6	8.2	—	V	I_E = 100µA, R_{BC} <1kΩ or 0.25V > V_{BC} > -0.25V
Emitter-Collector Breakdown Voltage (Reverse Blocking)	BV_{ECO}	6	8.7	—	V	I_E = 100µA
Emitter-Base Breakdown Voltage	BV_{EBO}	7	8.3	—	V	I_E = 100µA
Collector-Base Cutoff Current	I_{CBO}	—	<1	50 0.5	nA µA	V_{CB} = 180V V_{CB} = 180V, T_A = +100°C
Collector-Emitter Cutoff Current	I_{CEX}	—	—	100	nA	V_{CE} = 100V, R_{BE} <1kΩ or 1V < V_{BE} < 0.25V
Emitter Cutoff Current	I_{EBO}	—	<1	50	nA	V_{EB} = 5.6V
DC Current Transfer Static Ratio (Note 11)	h_{FE}	300 120 40 —	450 170 60 20	900 — — —	—	I_C = 10mA, V_{CE} = 2V I_C = 0.5A, V_{CE} = 2V I_C = 1A, V_{CE} = 2V I_C = 2.5A, V_{CE} = 2V
Collector-Emitter Saturation Voltage (Note 11)	$V_{CE(SAT)}$	—	120 80 220	170 100 345	mV	I_C = 0.5A, I_B = 10mA I_C = 1A, I_B = 100mA I_C = 2.5A, I_B = 250mA
Base-Emitter Saturation Voltage (Note 11)	$V_{BE(SAT)}$	—	935	1000	mV	I_C = 2.5A, I_B = 250mA
Base-Emitter Turn-on Voltage (Note 11)	$V_{BE(ON)}$	—	890	950	mV	I_C = 2.5A, V_{CE} = 2V
Transitional Frequency	f_T	—	175	—	MHz	I_E = 50mA, V_{CE} = 10V f = 100MHz
Input Capacitance	C_{IBO}		154	250	pF	V_{EB} = 0.5V, f = 1MHz
Output Capacitance	C_{OBO}	—	8.7	15	pF	V_{CB} = 10V, f = 1MHz
Delay Time	t_D	—	16.4	—	ns	I_C = 500mA, V_{CC} = 10V, I_{B1} = -I_{B2} = 50mA
Rise Time	t_R	—	115	—	ns	
Storage Time	t_S	—	763	—	ns	
Fall Time	t_F	—	158	—	ns	

Note: 11. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.

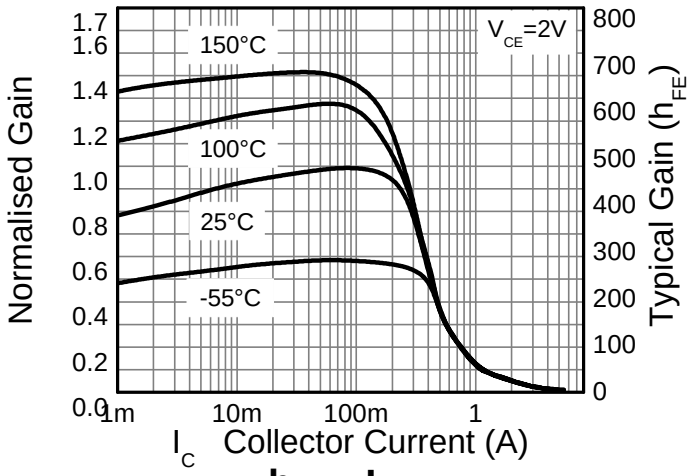
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



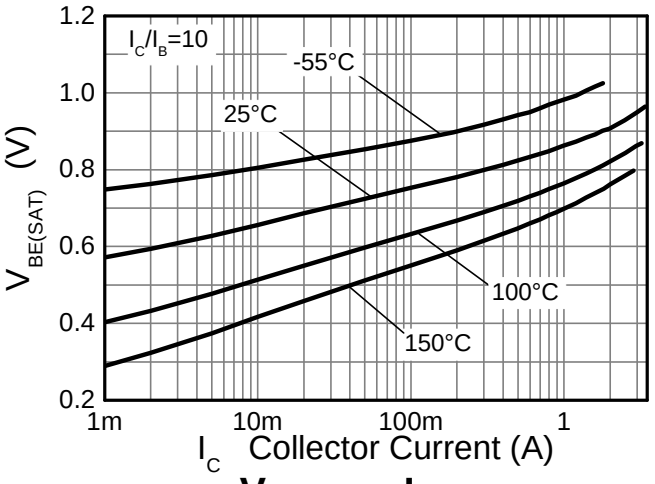
$V_{CE(SAT)}$ v I_C



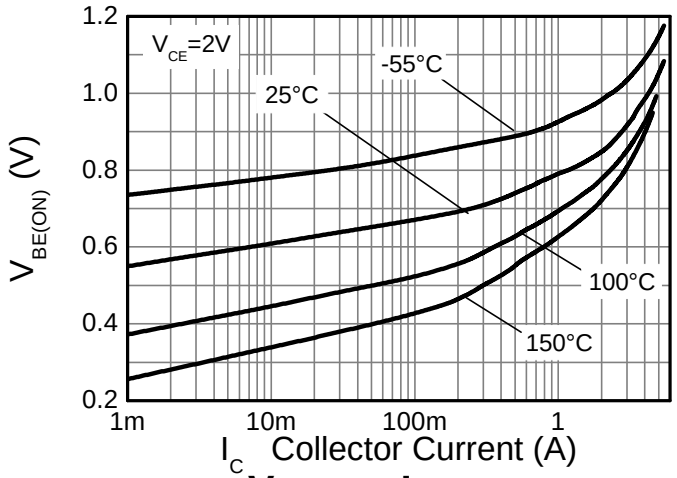
$V_{CE(SAT)}$ v I_C



h_{FE} v I_C



$V_{BE(SAT)}$ v I_C

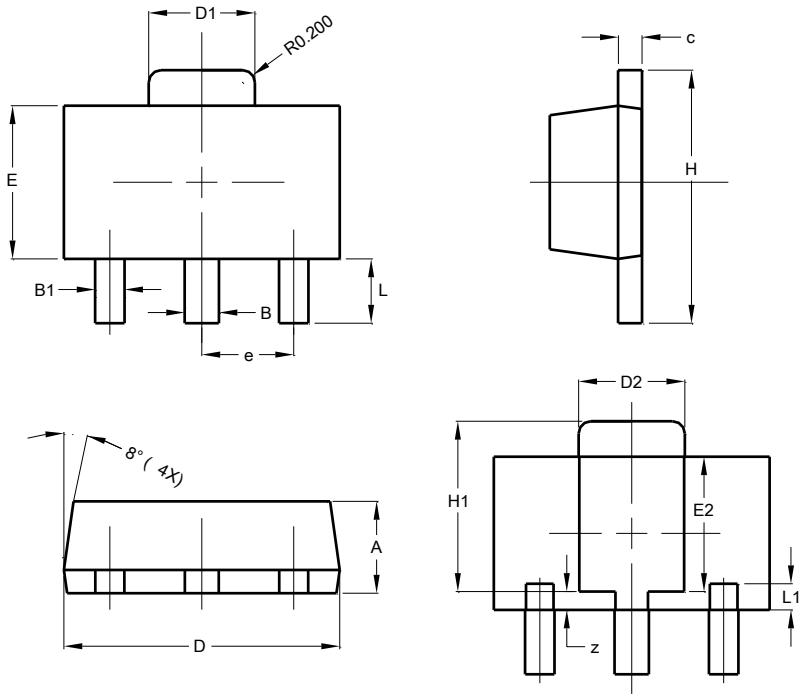


$V_{BE(ON)}$ v I_C

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89

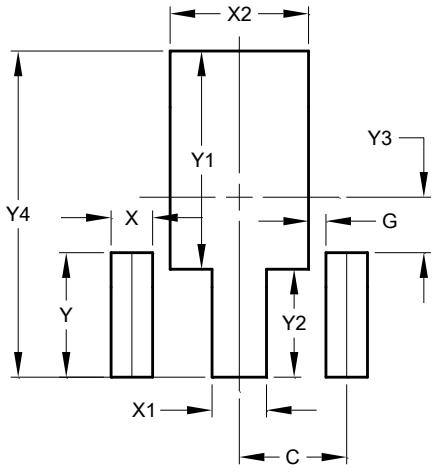


SOT89			
Dim	**Min**	**Max**	**Typ**
A	1.40	1.60	1.50
B	0.50	0.62	0.56
B1	0.42	0.54	0.48
c	0.35	0.43	0.38
D	4.40	4.60	4.50
D1	1.62	1.83	1.733
D2	1.61	1.81	1.71
E	2.40	2.60	2.50
E2	2.05	2.35	2.20
e	-	-	1.50
H	3.95	4.25	4.10
H1	2.63	2.93	2.78
L	0.90	1.20	1.05
L1	0.327	0.527	0.427
z	0.20	0.40	0.30
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89



Dimensions	Value (in mm)
C	1.500
G	0.244
X	0.580
X1	0.760
X2	1.933
Y	1.730
Y1	3.030
Y2	1.500
Y3	0.770
Y4	4.530

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.

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